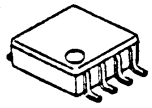
SPDT SWITCH GaAs MMIC

■GENERAL DESCRIPTION

NJG1516R is a GaAs SPDT switch IC suited for antenna switch of cellular phone handset.

This switch features low loss, high isolation at high power, and exhibits wide operating frequency range from 1MHz to 3GHz at low voltage of 2.7V.

■PACKAGE OUTLINE



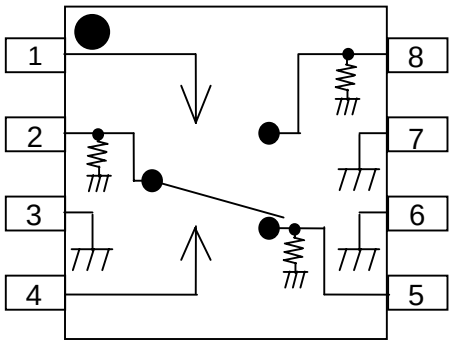
NJG1516R

■FEATURES

●Single, low voltage control	+2.7V min.
●Handling power	36dBm typ.@f=2GHz, V_{CTL}=3.0V
●Low insertion loss	0.4dB typ. @f=1GHz, P_{in}=31dBm, V_{CTL}=3V
	0.4dB typ. @f=1GHz, P_{in}=34.5dBm, V_{CTL}=3.5V
	0.55dB typ. @f=2GHz, P_{in}=31.5dBm, V_{CTL}=3V
●High isolation	27dB typ.@f=1GHz, P_{in}=34.5dBm, V_{CTL}=3.0V
	25dB typ.@f=2GHz, P_{in}=31.5dBm, V_{CTL}=3.0V
●Low current consumption	38uA typ.@f=2GHz, P_{in}=34.5dBm, V_{CTL}=3.0V
●Very small package	VSP8 (Mount Size: 4.0x2.9x1.2mm)

■PIN CONFIGURATION

R TYPE
(Top View)



Pin Connection

1.VCTL2
2.PC
3.GND
4.VCTL1
5.P1
6.GND
7.GND
8.P2

■TRUTH TABLE

"H"=$V_{CTL\ (H)}$, "L"=$V_{CTL\ (L)}$

V_{CTL1}	H	L
V_{CTL2}	L	H
PC - P1	ON	OFF
PC - P2	OFF	ON

■ABSOLUTE MAXIMUM RATINGS

(T_a=25°C)

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNITS
Input Power	P_{in}	$V_{CTL(L)}$=0V, $V_{CTL(H)}$=3.0V	38	dBm
Control Voltage	V_{CTL}	$V_{CTL(H)}$-$V_{CTL(L)}$	12	V
Power Dissipation	P_D		320	mW
Operating Temp.	T_{opr}		-40~+85	°C
Storage Temp.	T_{stg}		-55~+125	°C

■ELECTRICAL CHARACTERISTICS

($V_{CTL\ (L)}$=0V, $V_{CTL\ (H)}$=3V, Z_S=Z_I=50Ω, T_a=25°C)

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating Voltage (LOW)	$V_{CTL(L)}$		-0.2	0	0.2	V
Operating Voltage (HIGH)	$V_{CTL(H)}$	f=1GHz, P_{in}=34.5dBm	2.7	3.0	9.0	V
Control Current	I_{CTL}	f=1GHz, P_{in}=34.5dBm	-	38	55	uA
Insertion Loss 1	LOSS1	f=1GHz, P_{in}=31dBm	-	0.4	0.5	dB
Insertion Loss 2	LOSS2	f=1GHz, P_{in}=34.5dBm $V_{CTL(H)}$=3.5V, $V_{CTL(L)}$=0V	-	0.4	0.5	dB
Insertion Loss 3	LOSS3	f=1GHz, P_{in}=34.5dBm	-	0.4	0.6	dB
Insertion Loss 4	LOSS4	f=2GHz, P_{in}=31.5dBm	-	0.55	0.8	dB
Isolation 1 (PC-P1, PC-P2)	ISL1	f=1GHz, P_{in}=34.5dBm	26	27	-	dB
Isolation 2 (PC-P1, PC-P2)	ISL2	f=2GHz, P_{in}=31.5dBm	22	25	-	dB
Maximum Input Power 1 *1	P_{in1}	$V_{CTL(H)}$=2.7V, f=2GHz	-	-	33.5	dBm
Maximum Input Power 2 *1	P_{in2}	$V_{CTL(H)}$=3V, f=2GHz	-	-	34	dBm
Maximum Input Power 3 *1	P_{in3}	$V_{CTL(H)}$=4V, f=2GHz	-	-	37	dBm
Maximum Input Power 4 *1	P_{in4}	$V_{CTL(H)}$=6V, f=2GHz	-	-	38	dBm
Maximum Input Power 5 *1	P_{in5}	$V_{CTL(H)}$=9V, f=2GHz	-	-	34.5	dBm
Pout at 0.2dB Gain Compression point	$P_{-0.2dB}$1	f=2GHz	34.5	36	-	dBm
VSWR 1 (PC, P1, P2)	VSWR	f=0.05~2.5GHz, ON State	-	1.45	1.55	
Switching Time	T_{SW}	f=0.05~2.5GHz	-	70	-	ns

*1: Maximum Input Power: This value is defined as maximum input power of linear operating region or damage free operating region.

■**ELECTRICAL CHARACTERISTICS** (Cellular Band)

($V_{CTL\ (L)}$=0V, $V_{CTL\ (H)}$=2.7V, Z_S=Z_L=50Ω, T_a=25°C)

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Frequency range	f_{in}		800	-	1000	MHz
Control voltage (HIGH)	$V_{CTL(H)}$	P_{in}=25dBm	2.7	-	9	V
Insertion Loss 5	LOSS5	P_{in}=25dBm	-	0.4	0.5	dB
Isolation 3 (PC-P1, PC-P2)	ISL3	P_{in}=25dBm	26	27	-	dB
Pout at 0.2dB Gain Compression point 2	$P_{-0.2dB}$2		33.5	35	-	dBm
Input 3rd Order Intercept Point 1	IIP3(1)	f=900+901MHz, P_{in}=25dBm, $V_{CTL(H)}$=3V, $V_{CTL(L)}$=0V *2	-	62	-	dBm
Input 3rd Order Intercept Point 2	IIP3(2)	f=900+901MHz, P_{in}=25dBm $V_{CTL(H)}$=2.7V, $V_{CTL(L)}$=0V *2	-	60	-	dBm
Second Harmonics	2fo	f=900MHz, P_{in}=25dBm 2nd Harmonics of Input Signal = -83dBc		-80	-	dBc
Third Harmonics	3fo	f=900MHz, P_{in}=25dBm 3rd Harmonics of Input Signal =-100dBc	-	-70	-	dBc
VSWR 2 (PC, P1, P2)	VSWR2	ON State	-	1.15	1.25	

*2: The input IP3 is defined as following equation.

IIP3 = (3 x Pout – IM3) / 2 + LOSS

■TERMINAL INFORMATION

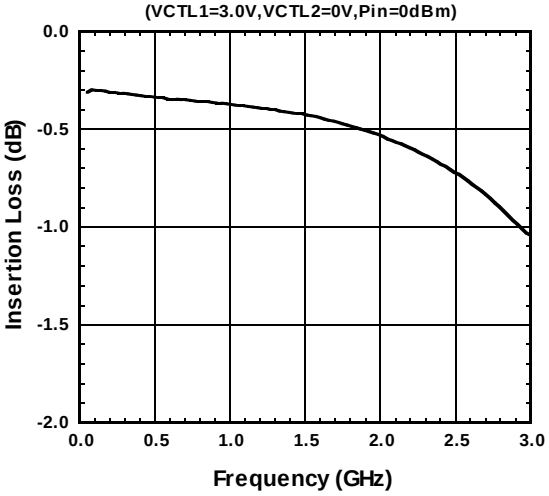
No.	SYMBOL	EXPLANATION
1	VCTL2	Control port 2. The voltage of this port controls PC to P2 state. The 'ON' and 'OFF' state is toggled by controlling voltage of this terminal such as high-state (2.7~5.5V) or low-state (-0.2~+0.2V). The voltage of 4th pin have to be set to opposite state. The bypass capacitor has to be chosen to reduce switching speed delay from 10pF~1000pF range.
2	PC	Common RF port. In order to block the DC bias voltage of internal circuit, an external capacitor is required. (50~100MHz: 0.01uF, 0.1~0.5GHz: 1000pF, 0.5~2.5GHz: 56pF)
3, 6, 7	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
4	VCTL1	Control port 1. The voltage of this port controls PC to P2 state. The 'ON' and 'OFF' state is toggled by controlling voltage of this terminal such as high-state (2.7~5.5V) or low-state (-0.2~+0.2V). The voltage of 1st pin have to be set to opposite state. The bypass capacitor has to be chosen to reduce switching speed delay from 10pF~1000pF range.
5	P1	RF port. This port is connected with PC port by controlling 4th pin ($V_{CTL\ (H)}$) to 2.7~9.0V and 1st pin ($V_{CTL\ (L)}$) to -0.2~+0.2V. An external capacitor is required to block the DC bias voltage of internal circuit. (50~100MHz: 0.01µF, 0.1~0.5GHz: 1000pF, 0.5~2.5GHz: 56pF)
8	P2	RF port. This port is connected with PC port by controlling 1st pin ($V_{CTL\ (H)}$) to 2.7~9.0V and 4th pin ($V_{CTL\ (L)}$) to -0.2~+0.2V. An external capacitor is required to block the DC bias voltage of internal circuit. (50~100MHz: 0.01µF, 0.1~0.5GHz: 1000pF, 0.5~2.5GHz: 56pF)

■ELECTRICAL CHARACTERISTICS

(f=50MHz~3.0GHz, with application circuit, losses of external circuit are excluded)

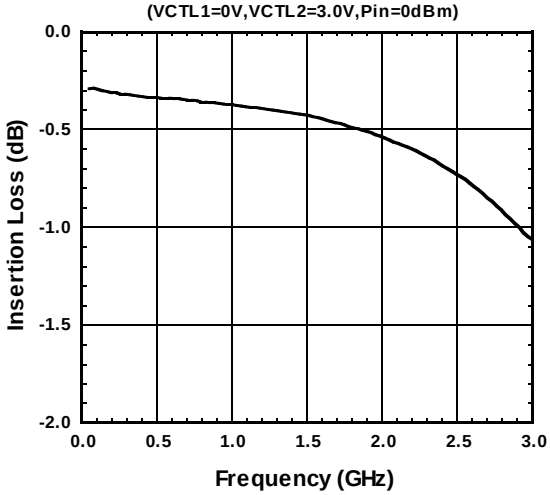
PC-P1 Insertion Loss vs. Frequency

(VCTL1=3.0V,VCTL2=0V,Pin=0dBm)



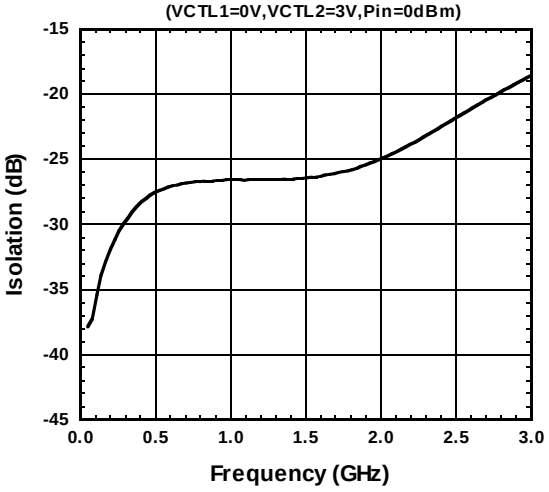
PC-P2 Insertion Loss vs. Frequency

(VCTL1=0V,VCTL2=3.0V,Pin=0dBm)



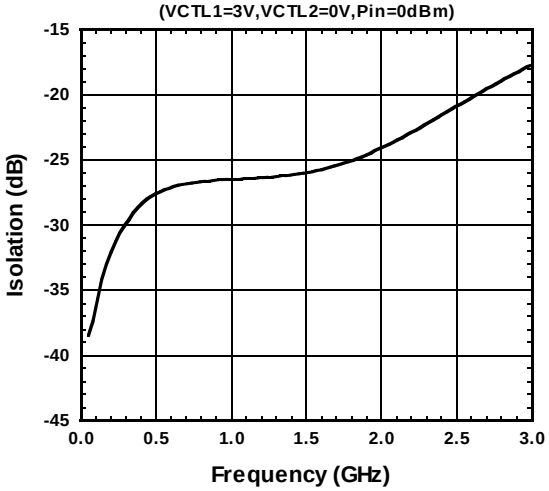
PC-P1 Isoration vs. Frequency

(VCTL1=0V,VCTL2=3V,Pin=0dBm)



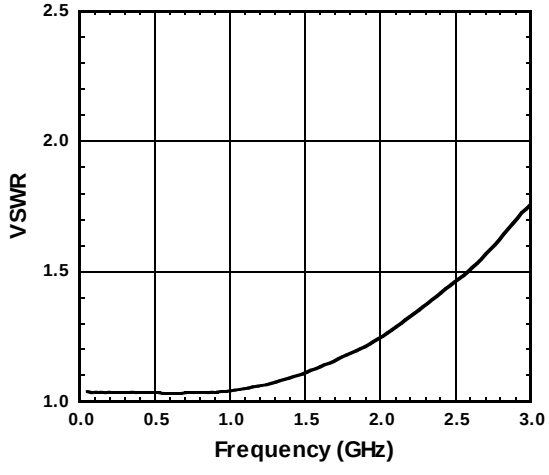
PC-P2 Isoration vs. Frequency

(VCTL1=3V,VCTL2=0V,Pin=0dBm)



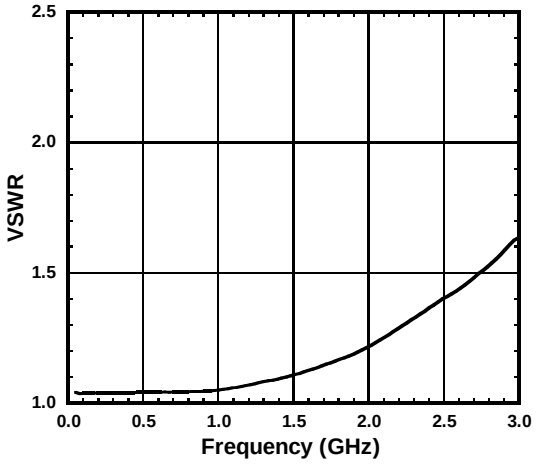
PC-P1 VSWR vs. Frequency

(VCTL1=3V,VCTL2=0V,PC port)



PC-P1 VSWR vs. Frequency

(VCTL1=3V, VCTL2=0V, P1 port)

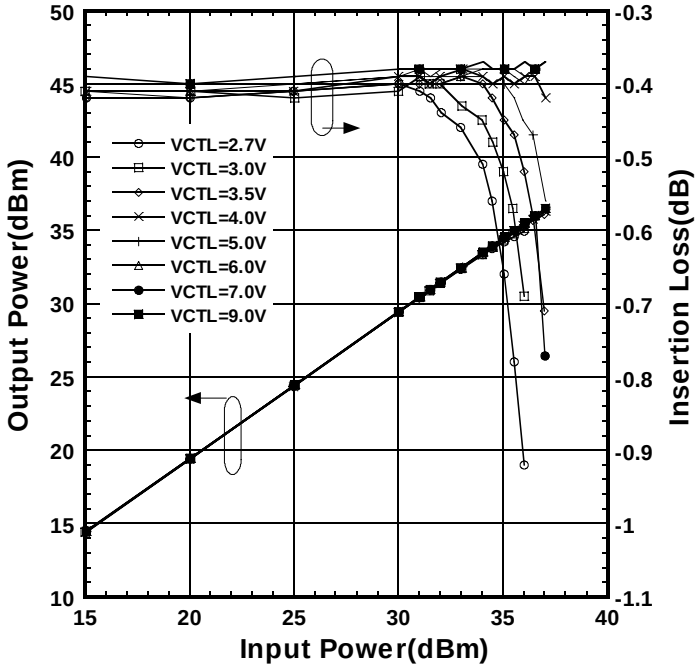


■ELECTRICAL CHARACTERISTICS

(f=1.0GHz, with application circuit (Parts list 3), losses of PCB, connector and DC blocking capacitor are excluded)

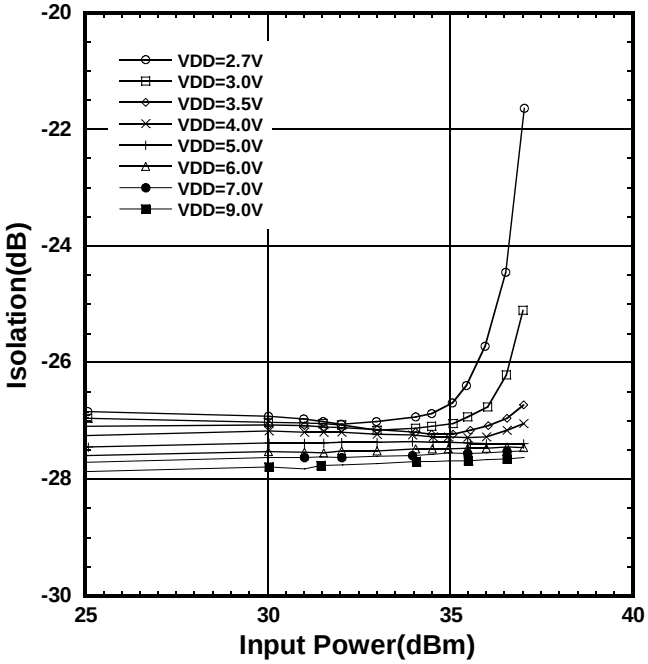
Output Power,Insertion Loss vs. Input power

(PC-P1,f=1GHz)



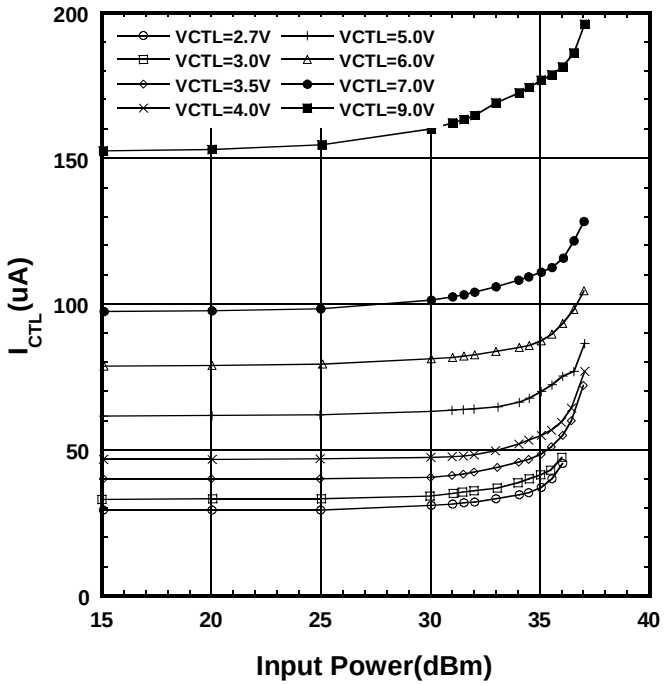
PC-P1 Isolation vs. Input Power

(PC-P1,f=1GHz)



I_{CTL} vs. Input Power

(PC-P1,f=1GHz)

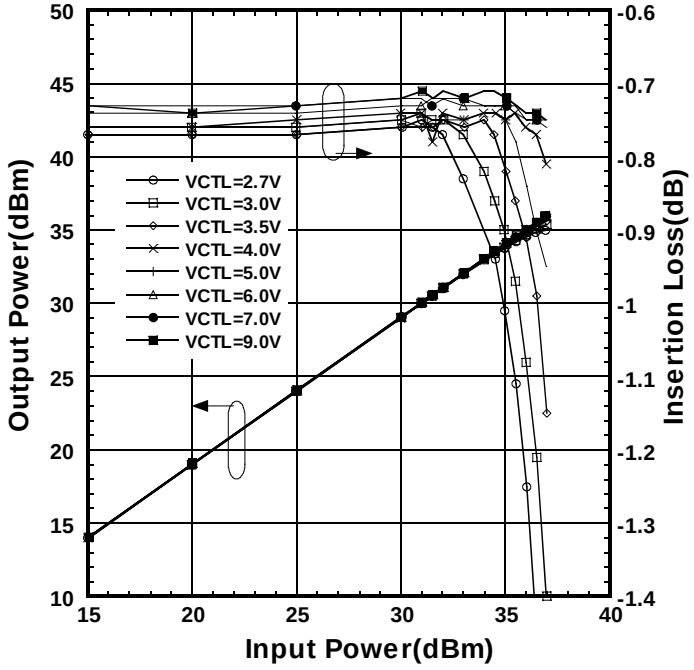


■ELECTRICAL CHARACTERISTICS

(f=2.0GHz, with application circuit (Parts list 3), losses of PCB, connector and DC blocking capacitor are excluded)

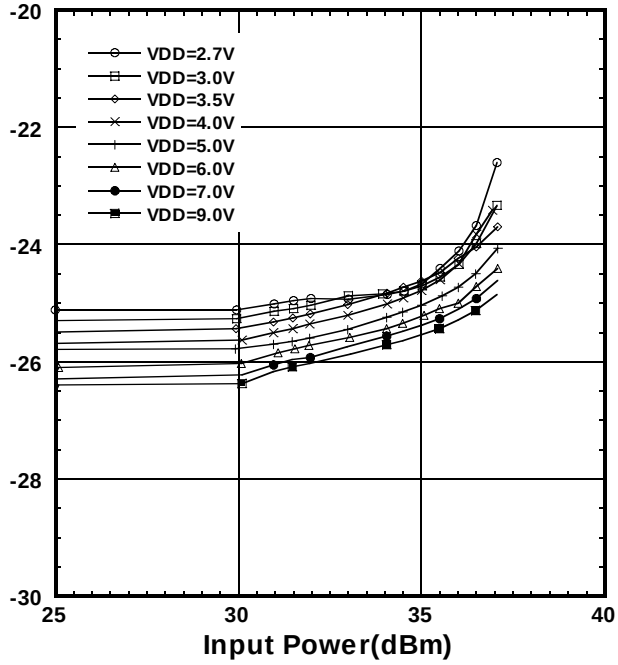
Output Power,Insertion Loss vs. Input power

(PC-P1,f=2GHz)



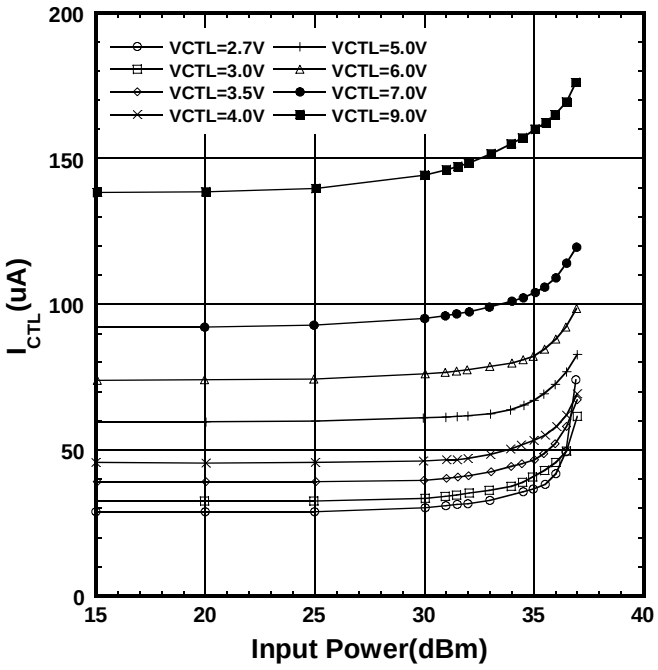
PC-P1 Isoration vs. Input Power

(PC-P1,f=2GHz)



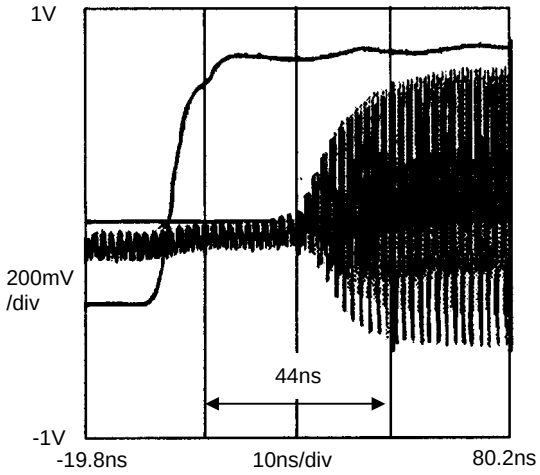
I_{CTL} vs. Input Power

(PC-P1,f=2GHz)

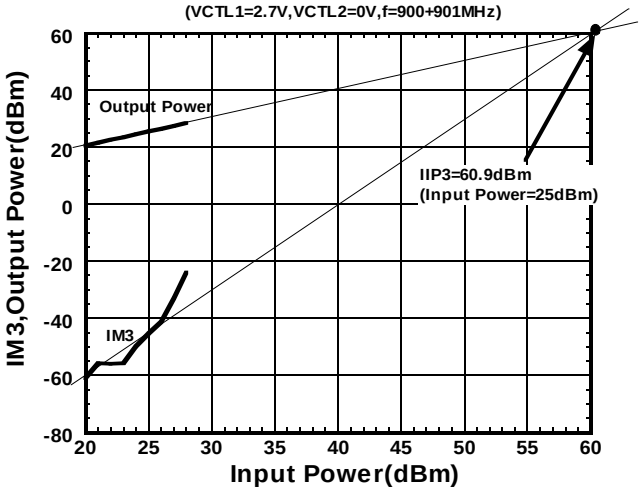


■**ELECTRICAL CHARACTERISTICS** (with application circuit, Parts list 3)

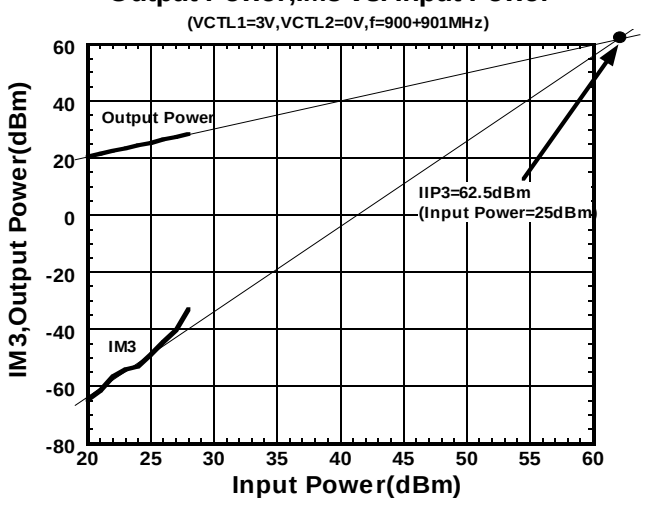
Switching speed
(V_{CTL1}=3.0V, V_{CTL2}=0V)



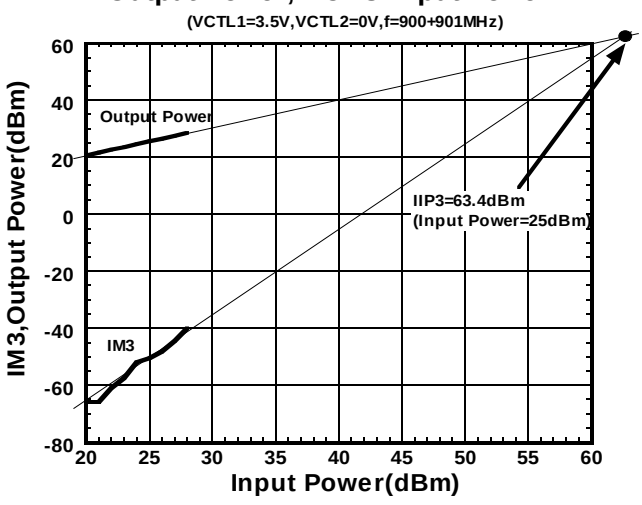
Output Power,IM3 vs. Input Power



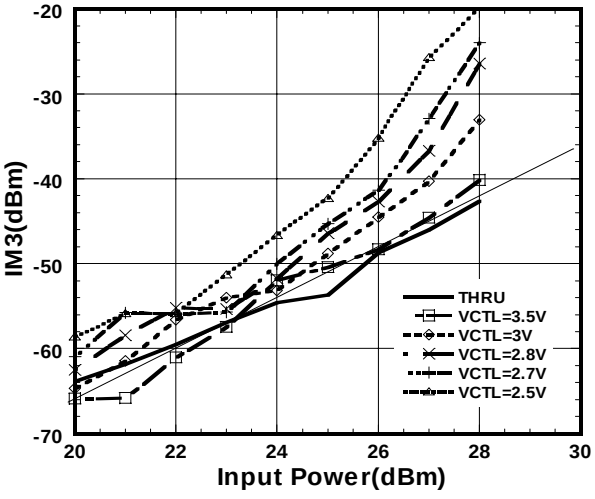
Output Power,IM3 vs. Input Power



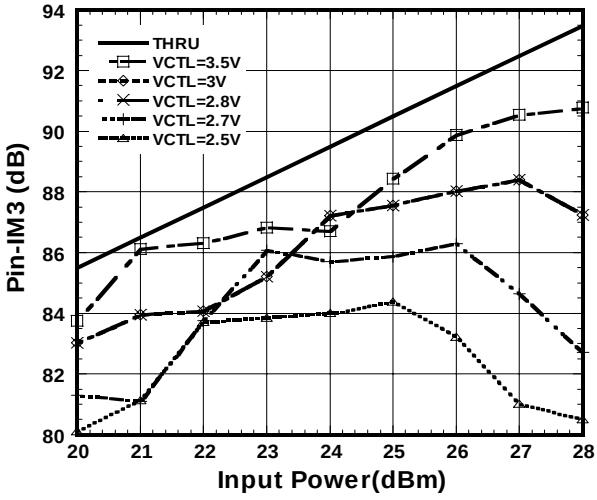
Output Power,IM3 vs. Input Power



IM3 vs. Input Power



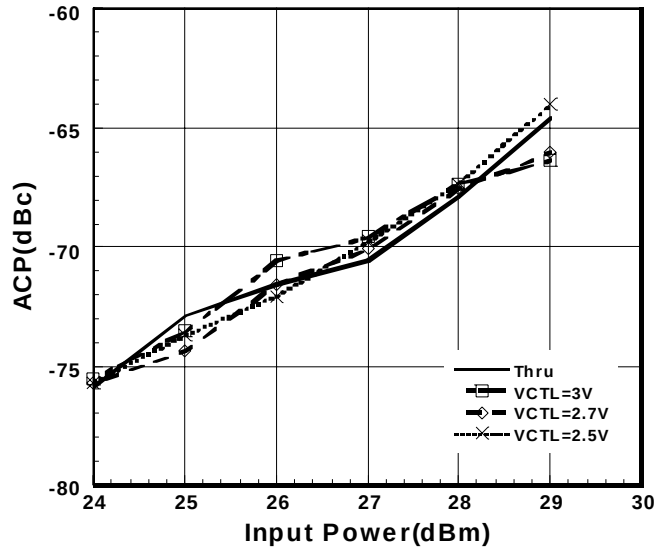
Pin-IM3 vs. Input Power



■**ELECTRICAL CHARACTERISTICS** (with application circuit, Parts list 3)

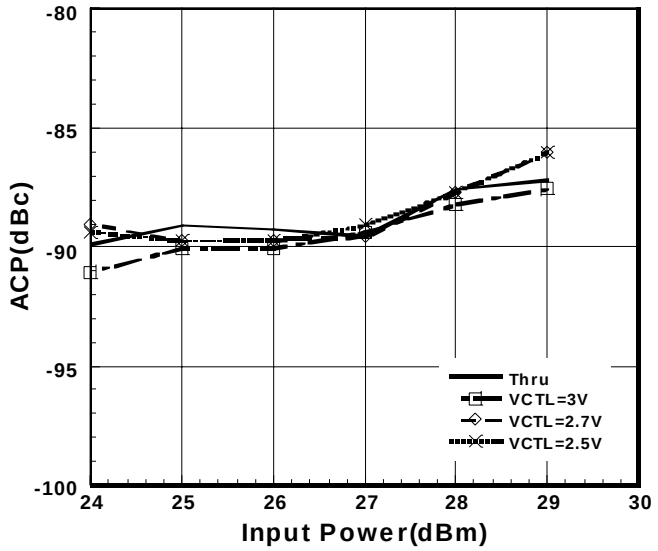
ACP vs. Input Power

(f=1GHz,offset=0.9MHz)



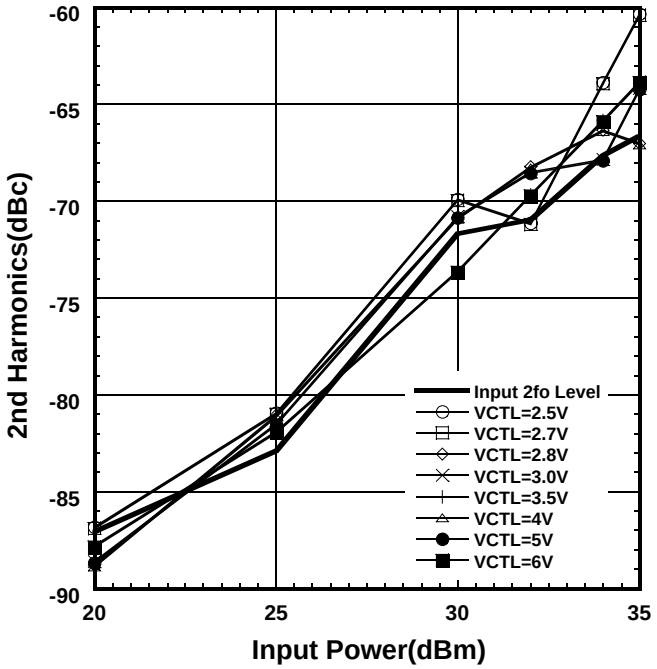
ACP vs. Input Power

(f=1GHz,offset=1.98MHz)



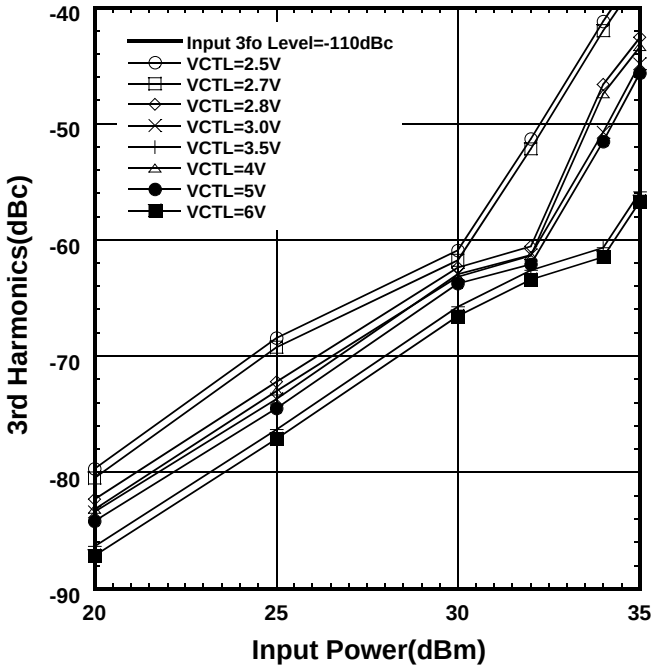
2nd Harmonics vs. Input Power

(f=900MHz)



3rd Harmonics vs. Input Power

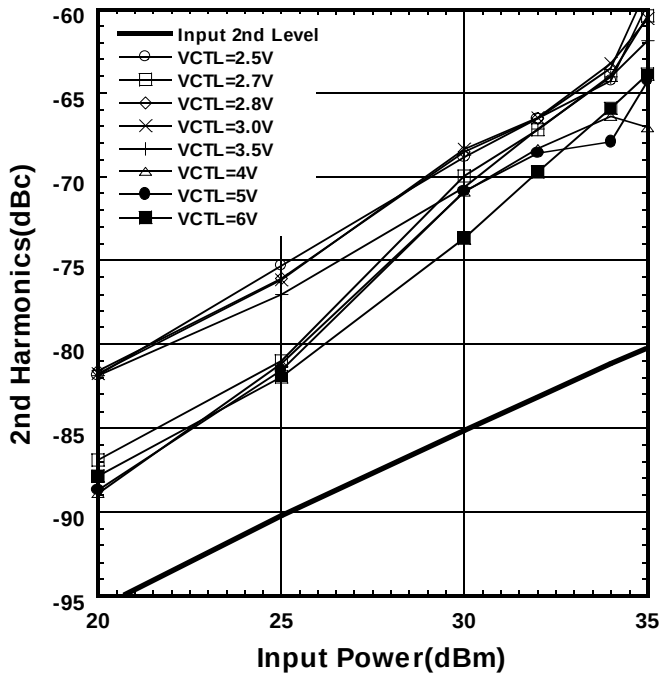
(f=900MHz)



■**ELECTRICAL CHARACTERISTICS** (with application circuit, Parts list 3)

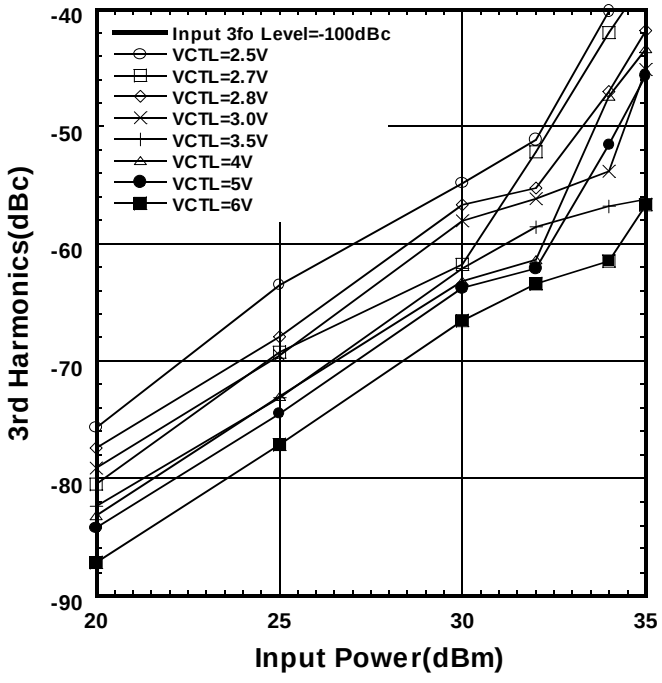
2nd Harmonics vs. Input Power

(f=1800MHz)



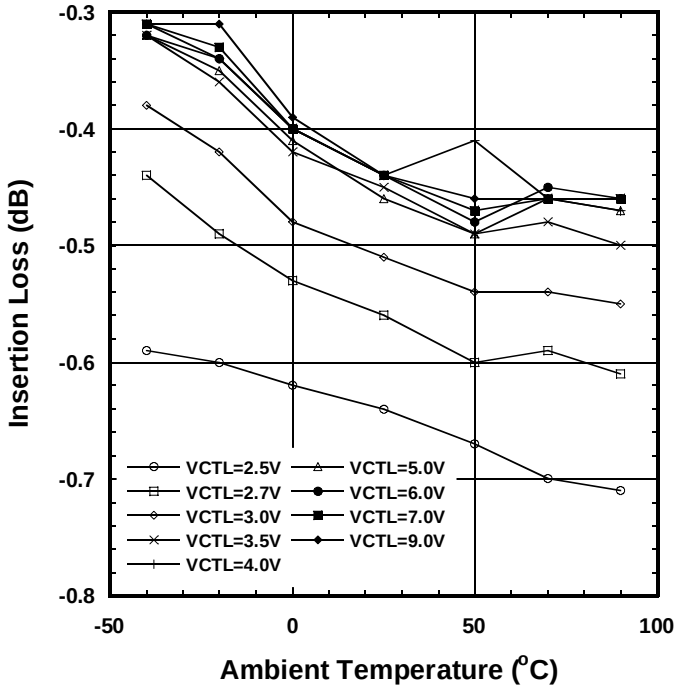
3rd Harmonics vs. Input Power

(f=1800MHz)



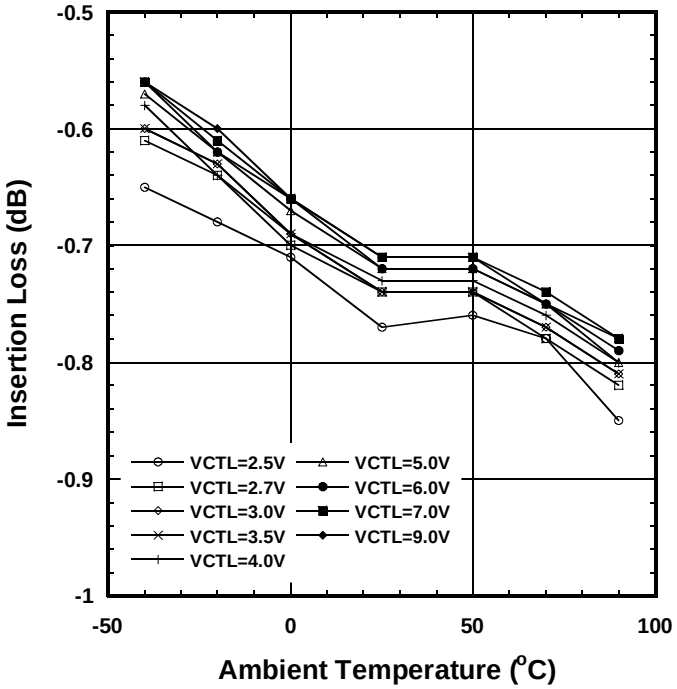
Insertion Loss vs. Ambient Temperature

(PC-P1,f=1GHz,Input Power=34.5dBm)



Insertion Loss vs. Ambient Temperature

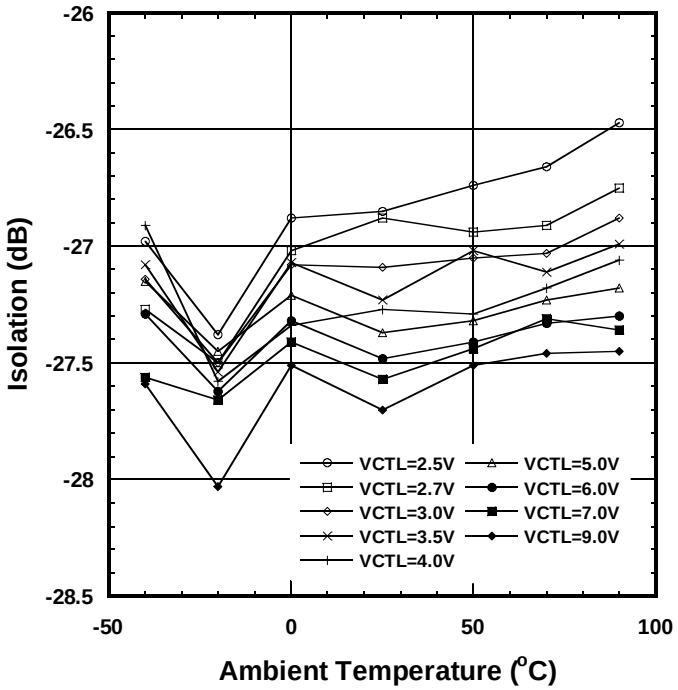
(PC-P1,f=2GHz,Input Power=31.5dBm)



■**TEMPERATURE CHARACTERISTICS** (with application circuit, Parts list 3)

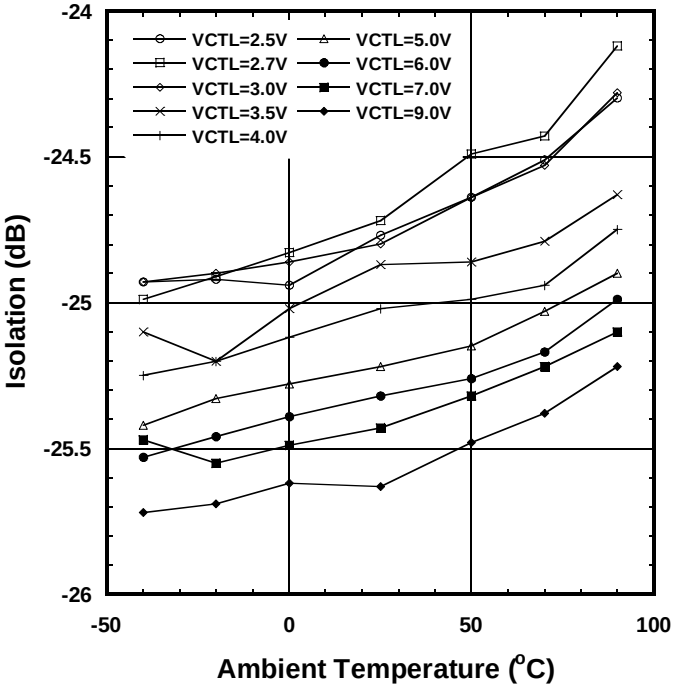
Isolation vs. Ambient Temperature

(PC-P1,f=1GHz,Input Power=34.5dBm)



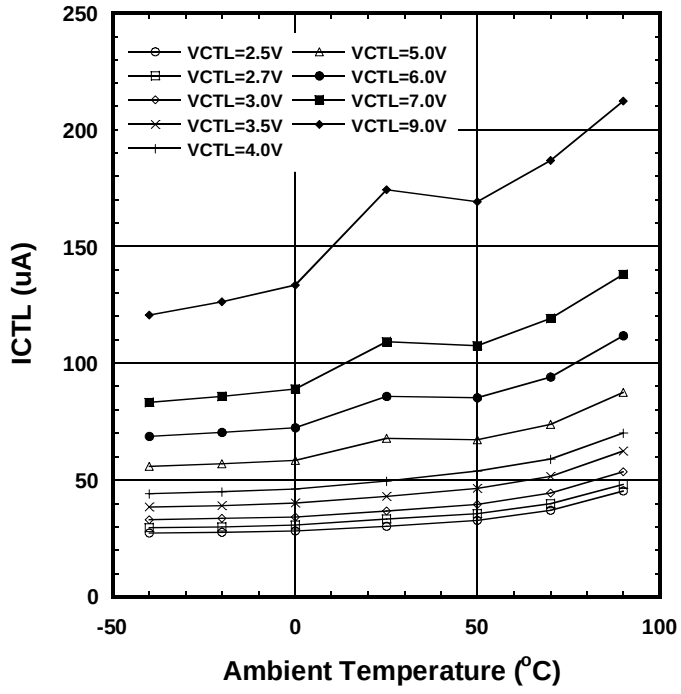
Isolation vs. Ambient Temperature

(PC-P1,f=2GHz,Input Power=31.5dBm)



ICTL vs. Ambient Temperature

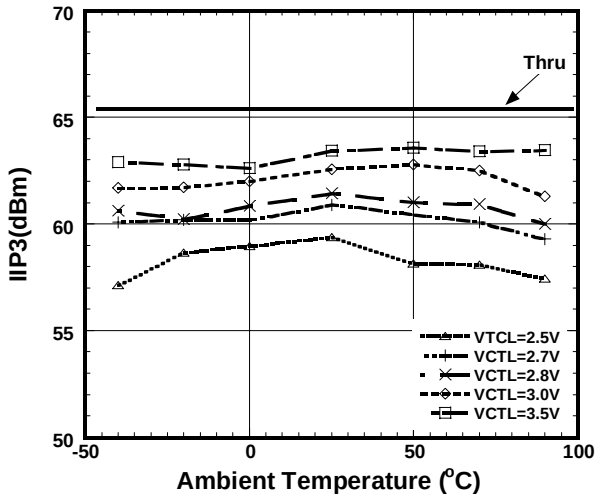
(PC-P1,f=1GHz,Input Power=34.5dBm)



■TEMPERATURE CHARACTERISTICS (with application circuit, Parts list 3)

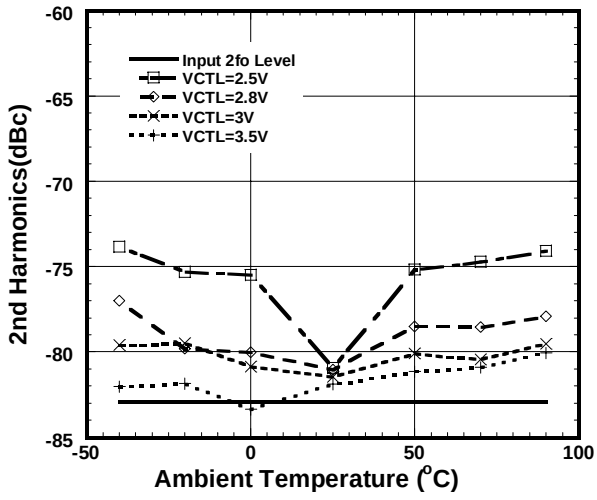
IIP3 vs. Ambient Temperature

(PC-P1,f=900+901MHz,Input Power=25dBm)



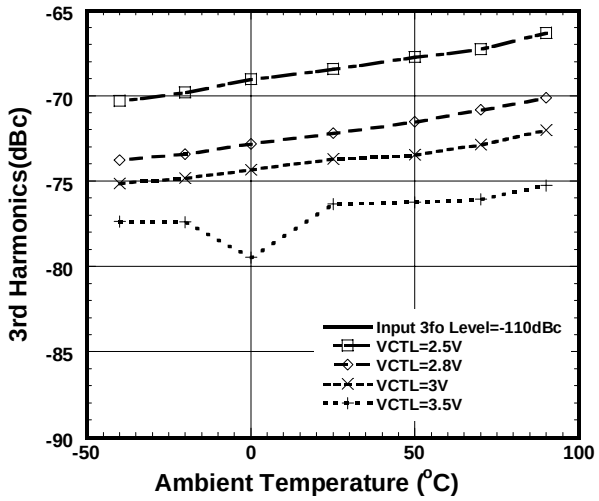
2nd Harmonics vs. Ambient Temperture

(f=900MHz,Input Power=25dBm)



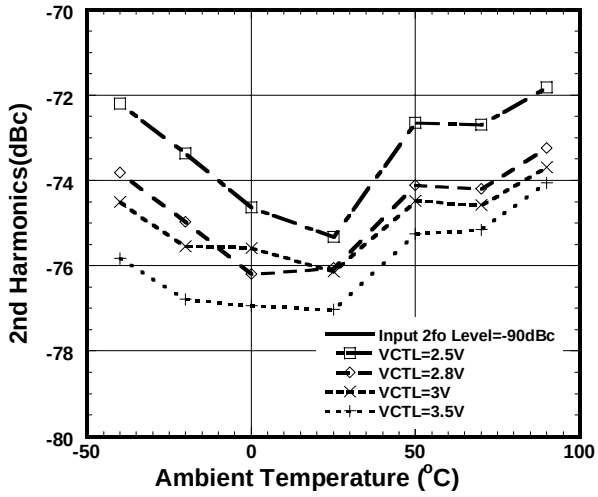
3rd Harmonics vs. Ambient Temperture

(f=900MHz,Input Power=25dBm)



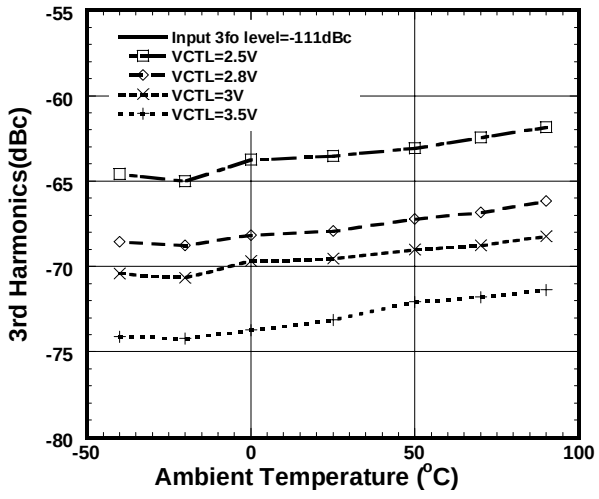
2nd Harmonics vs. Ambient Temperture

(f=1800MHz,Input Power=25dBm)

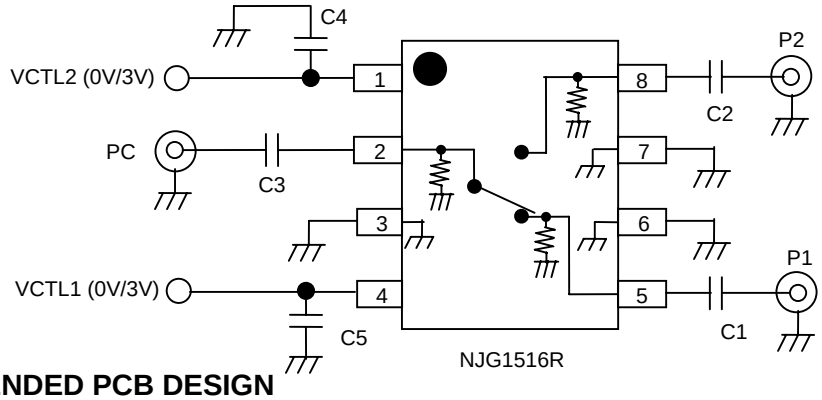


3rd Harmonics vs. Ambient Temperture

(f=1800MHz,Input Power=25dBm)

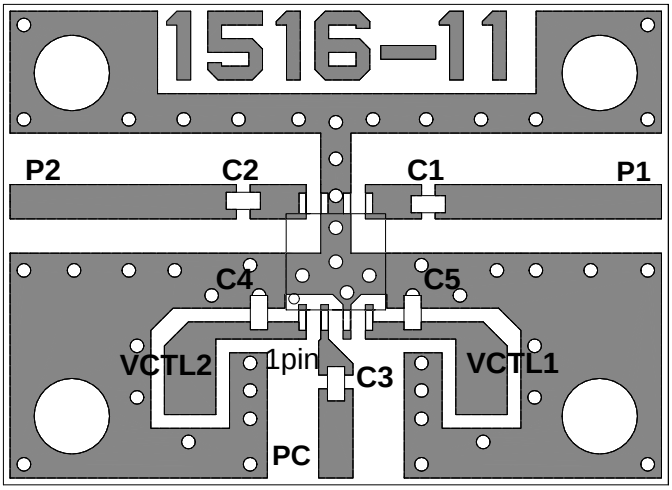


■APPLICATION CIRCUIT



■RECOMMENDED PCB DESIGN

(TOP VIEW)



PCB: FR-4, t=0.5mm

Capacitor: size 1005

Microstrip Line Width=1.0mm (Zo=50Ω)

PCB SIZE: 19.4 x 14mm

■Circuit losses including losses of capacitors and connectors.

Frequency (GHz)	Loss (dB)
0.8	0.12
1.0	0.13
1.5	0.17
1.8	0.19
2.0	0.20
2.5	0.26

■PARTS LIST

PART ID	1	2	3
Freq(MHz)	50~100	100~500	500~2000
C1~C3	0.01uF	1000pF	56pF
C4, C5	10pF	10pF	10pF

PRECAUTIONS

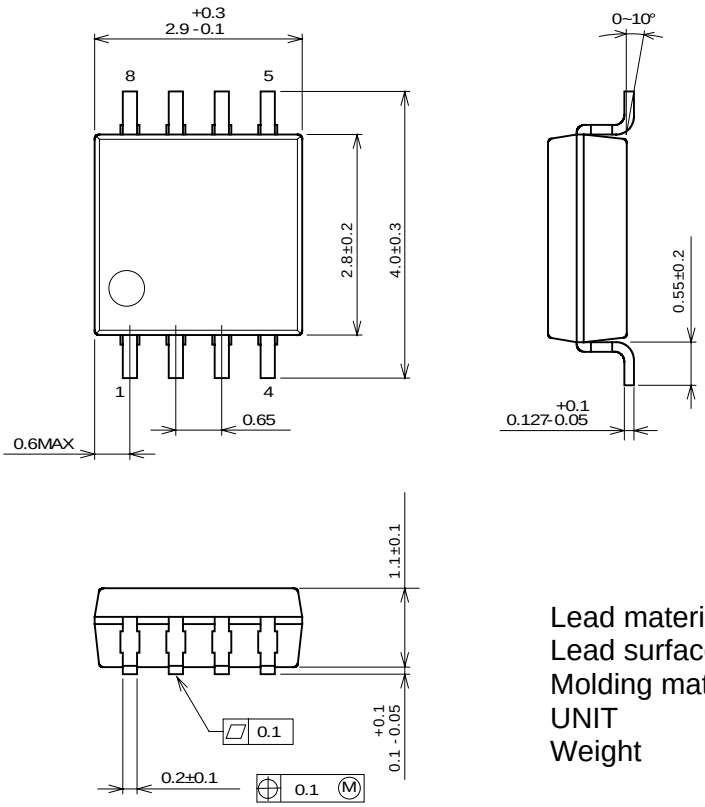
[1]The DC blocking capacitors have to be placed at RF terminal of P1, P2 and PC.

[2]Bypass capacitors (C4, C5) should be placed close to terminals of VCTL1, VCTL2 to reduce stripline influence of RF characteristics.

[3]For good isolation, the GND terminal (3^{rd}, 6^{th}, 7^{th} pin) must be placed possibly close to ground plane of substrate, and through holes for GND should be placed near by the pin connection.

[4] To avoid degradation of isolation or high power characteristics, please layout ground pattern right under this IC.

■PACKAGE OUTLINE



Lead material	: Copper
Lead surface finish	: Solder plating
Molding material	: Epoxy resin
UNIT	: mm
Weight	: 22mg

Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.